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VS-85EPF12 Soft Recovery Series

**Vishay Semiconductors** 

Fast Soft Recovery Rectifier Diode, 85 A

# Cathode Anode

PowerTab<sup>®</sup>

# LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	85 A			
V <sub>R</sub>	1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.36 V			
I <sub>FSM</sub>	1250 A			
t <sub>rr</sub>	95 ns			
T <sub>J</sub> max.	150 °C			
Snap factor	0.5			
Package	PowerTab <sup>®</sup>			
Circuit configuration	Single			

### FEATURES

- Glass passivated pellet chip junction
- 150 °C max. operating junction temperature
- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met
- Screw mounting only
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- PowerTab<sup>®</sup> package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-85EPF12 fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions. Available in the new PowerTab package, this new series is suitable for a large range of applications combining excellent die to footprint ratio and sturdiness connectivity for use in high current environments.

## **MECHANICAL DATA**

### Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating **Terminal:** nickel plated, screwable

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNITS					
I <sub>F(AV)</sub>	Rect. conduction 50 % duty cycle at $T_C = 85 \ ^{\circ}C$	85	۸				
I <sub>F(RMS)</sub>		160	A				
V <sub>RRM</sub>		1200	V				
I <sub>FSM</sub>		1250	А				
V <sub>F</sub>	100 A, T <sub>J</sub> = 25 °C	1.4	V				
t <sub>rr</sub>	1 A, - 100 A/μs	95	ns				
TJ	Range	-40 to +150	°C				

VOLTAGE RATINGS			
TYPE NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA
VS-85EPF12	1200	1300	15

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 85 \text{ °C}, 180^\circ \text{ conduction half sine wave}$	85		
Maximum peak one cycle non-repetitive surge current	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied	1100	А	
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, no voltage reapplied	1250		
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	5000 A <sup>2</sup> s		
		10 ms sine pulse, no voltage reapplied	7000	A-S	
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	70 000	A²√s	

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FI	FCTR	ICAL	SPEC	IFICAT	<b>IONS</b>

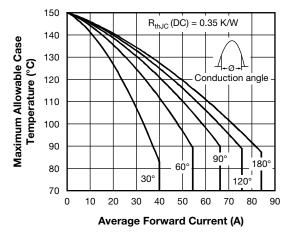
ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		UNITS	
Maximum forward voltage drop	V <sub>FM</sub>	85 A, T <sub>J</sub> = 25 °C		1.36	V	
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> = 150 °C		4.03	mΩ	
Threshold voltage	V <sub>F(TO)</sub>			0.87	V	
Maximum reverse leakage current		T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>BBM</sub>	0.1	mA	
Maximum reverse leakage current		T <sub>J</sub> = 150 °C	VR - naieu VRRM	15		

RECOVERY CHARACTERISTICS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Reverse recovery time	t <sub>rr</sub>	In at 85 Anic	480	ns	I <sub>FM</sub> t	
Reverse recovery current	I <sub>rr</sub>	l <sub>F</sub> at 85 A <sub>pk</sub> 25 A/μs	7.1	А		
Reverse recovery charge	Q <sub>rr</sub>	25 °C	2.1	μC	$\frac{\text{dir}}{\text{dt}}$	
Snap factor	S		0.5			

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and s temperature range	torage	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resista junction to case	ance,	R <sub>thJC</sub>	DC operation	0.35	
Maximum thermal resista junction to ambient	ance,	R <sub>thJA</sub>		40	°C/W
Typical thermal resistanc case to heatsink	æ,	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2	
Approximate weight				6	g
Approximate weight				0.21	oz.
Mounting torque	minimum			6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf ⋅ in)
Marking device	Iarking device Case style PowerTab <sup>®</sup> 85EPF12		PF12		



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Fig. 1 - Current Rating Characteristics

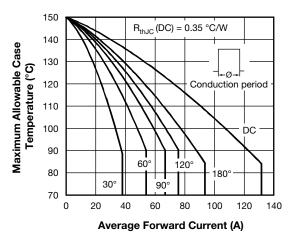


Fig. 2 - Current Rating Characteristics

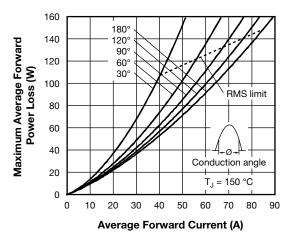


Fig. 3 - Forward Power Loss Characteristics

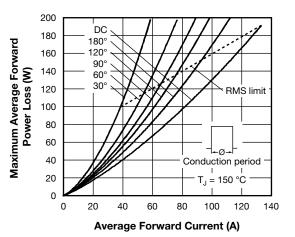
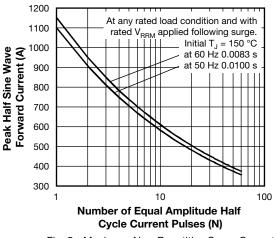


Fig. 4 - Forward Power Loss Characteristics





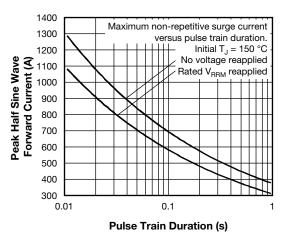


Fig. 6 - Maximum Non-Repetitive Surge Current

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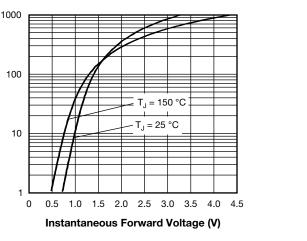


Fig. 7 - Forward Voltage Drop Characteristics

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Instantaneous Forward Current (A)

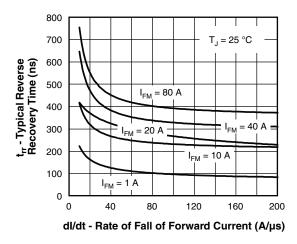


Fig. 8 - Recovery Time Characteristics,  $T_J = 25 \ ^{\circ}C$ 

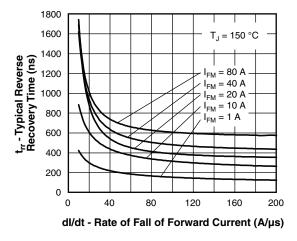


Fig. 9 - Recovery Time Characteristics,  $T_J = 150 \ ^\circ C$ 

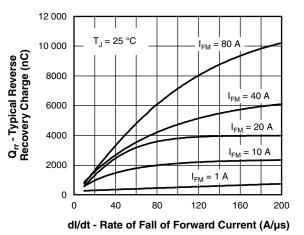


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25 \degree C$ 

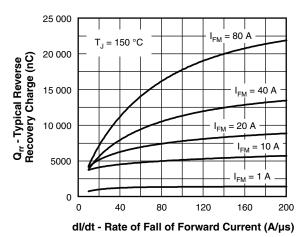


Fig. 11 - Recovery Charge Characteristics,  $T_J = 150 \text{ }^{\circ}\text{C}$ 

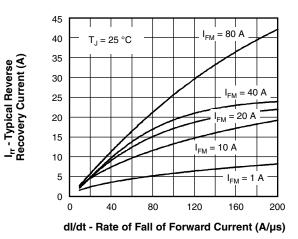


Fig. 12 - Recovery Current Characteristics,  $T_J = 25$  °C

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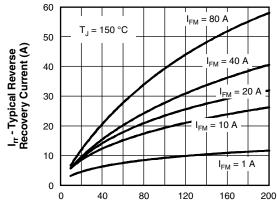
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dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics,  $T_J$  = 150 °C

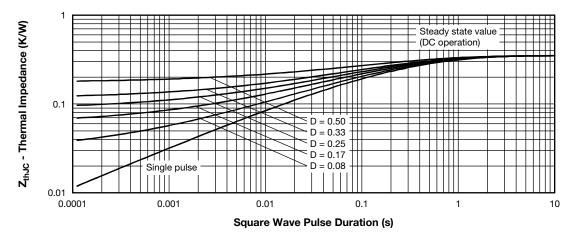


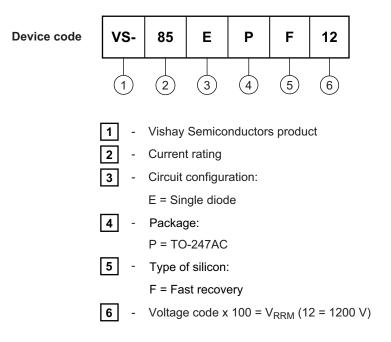
Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics



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# **ORDERING INFORMATION TABLE**



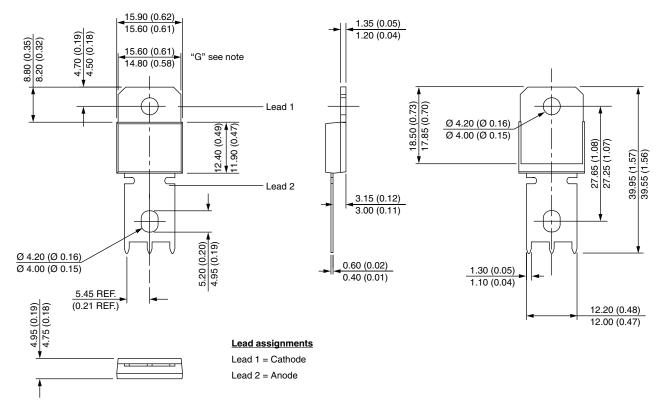
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95240				
Part marking information	www.vishay.com/doc?95370			
Application note	www.vishay.com/doc?95179			
SPICE model	www.vishay.com/doc?96894			



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# **DIMENSIONS** in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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